DS06-70105-3E

Semicustom

ASTRO-NT

(for RF front-end LSI-Based on PLL, Analog Macro)

MB15G000 Series

■ DESCRIPTION

The ASTRO-NT* is a new technology to correspond to the demand of high performance RF LSI. The technology stands on a macro concept and create a custom LSI ideal for use in high frequency front-end circuit such as VCO, amplifier, mixer and I/Q modulator devices.

The chip can be built by combining macros, in accordance with user's demand function and characteristic. FUJITSU prepares standard RF macros. They are well finished in design and layout to fulfil good performance by function that a master slice method can not achive. It is possible to modify RF macro in response to user's demand.

This LSI series uses FUJITSU's latest BiCMOS process technology for low current consumption. In addition, many types of packages are available that makes it possible to find a proper size package for different circuit integration levels.

ASTRO-NT is ideal for applications with RF or IF signal, particularly mobile communication devices operating such as PDC, PHS, GSM, DCS, PCS and so on.

*: Advanced Standard macro base Technology of PLL with RF system On LSI-New Technology

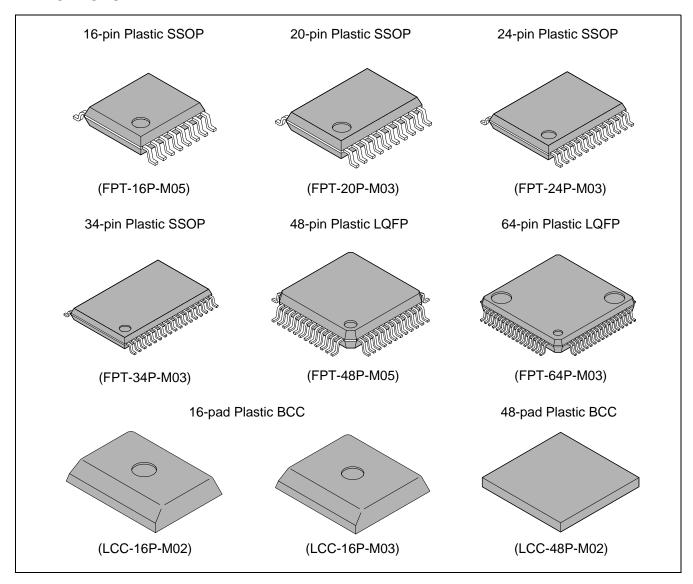
■ FEATURES

- High operating frequency: to 3.0 GHz (max)
- Supply voltage: 2.5 to 5.5 V
- · Standard RF macro
- Low power consumption
- Package line up –Many types of package are available.

SSOP-16, SSOP-20, SSOP-24, SSOP-34, BCC-16, BCC-48, LQFP-48, LQFP-64,

- Operating temperature: –40 to +85°C
- Fujitsu's latest BiCMOS process technology

■ PACKAGES



Number of pins and name of package	Package Code	Size (mm)
16-pin Plastic SSOP	FPT-16P-M05	$6.4 \times 5.0 \times 1.25$
20-pin Plastic SSOP	FPT-20P-M03	$6.4 \times 6.5 \times 1.25$
24-pin Plastic SSOP	FPT-24P-M03	$7.6 \times 7.75 \times 1.25$
34-pin Plastic SSOP	FPT-34P-M03	8.1 × 11.0 × 1.25
48-pin Plastic LQFP	FPT-48P-M05	9.0 × 9.0 × 1.5
64-pin Plastic LQFP	FPT-64P-M03	12.0 × 12.0 × 1.5
16-pad Plastic BCC	LCC-16P-M02	$3.4\times4.55\times0.8$
10-pau Flasiic BCC	LCC-16P-M03	$4.2\times4.55\times0.8$
48-pad Plastic BCC	LCC-48P-M02	$7.0\times7.0\times0.8$

■ ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Ra	Unit	
	Symbol	Min.	Max.	Unit
Power supply voltage *1	Vcc *2	-0.5	4.0	V
	Vcc *3	-0.5	6.0	V
Input voltage *1	Vin	-0.5	Vcc + 0.5	V
Output current	lout	-10	10	mA
Storage temperature	Tstg	- 55	+125	°C

^{*1:}Voltage values are based on GND = 0 V

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol		Unit		
	Symbol	Min.	Тур.	Max.	Offic
	Vcc *2,*3	2.7	3.0	3.3	V
Power supply voltage *1	Vcc *2,*4	4.5	5.0	5.5	V
	GND	_	0	_	V
Input voltage	Vin	GND	_	Vcc	V
Operating temperature	Та	-40	_	+85	°C

^{*1:}Voltage values are based on GND = 0 V

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

^{*2:}Using 3V macro specifications

^{*3:}Using 5V macro specifications

^{*2:}The range of operating voltage should be defined depends on circuit configuration.

For models not using standard 3V or 5V specifications, maximum ratings and recommended operating conditions are set according to circuit use.

^{*3:}Using 3V macro specifications

^{*4:}Using 5V macro specifications

■ MACRO DESCRIPTIONS

1. Prescaler

Divides the reference frequency by any given value and outputs the resulting frequency. Choice of two -modulus or fixed output mode.

2. PLL

Phase comparator

The phase comparator has a phase detection range of -2π to $+2\pi$, and is designed to eliminate blind spots in phase comparison by output of a margin-of-error signal to the charge pump even when the phase difference is zero. Phase comparator characteristics can also be tuned to the polarity of VCO.

Counters

The divide ratios of the comparator-side counter and reference-side counter can be either programmable or fixed.

Charge pump

The "H" level output voltage from the charge pump is determined by power supply voltage. Charge pump characteristics for the sending and receiving systems can be optimized for each specific application.

For example, when FM modulation is applied directly to the VCO signal, charge pump characteristic can be adjusted for lower speeds in order to reduce the sensitivity of the synthesizer loop so that output does not track the modulation.

• High speed lock-up circuit

This circuit is specially designed for faster lock-up speeds.

• Intermittent operation control circuit

This on-chip power-saving function reduces circuit current flow in standby status, enabling devices to operate with less power demand. A special circuit is built in to prevent excessive error signal from increasing lock-up delay during the transition from power-saving mode to operating mode.

· List of standard macros

Туре	Vcc	Icc	Operating frequency	Prescaler divide ratio (M)	Comparator counter divide ratio (N)	Swallow counter divide ratio (A)	Reference counter divide ratio (R)
PLL1		1.5 mA	0.5 GHz	8/9, 16/17			
PLL2	2.7 V	2.0 mA 1.2	1.2 GHz		5 to 2047	0 to 255	5 to 16383
PLL3	2.7 V	3.0 mA	2.0 GHz	32/33, 64/65			
PLL4		3.5 mA	2.5 GHz				

Crystal oscillator input frequency: Up to 32 MHz

Standby mode current demand: 10 µA(Max.)

Note: Refer to macro specification book.

3. RF Analog Macro List

Circuit	Function	Voltage	Current	Application Example		
	900 MHz QMOD + AGC			29.6 mA	PDC	
	1.9 GHz MOD + UpCONV (IF =	= 233 MHz)		27.0 mA	PHS	
	0.9, 1.9 GHz Doubler + MOD Uր	CONV IF = 413 MHz	3.0 V	28.0 mA	GSM/DCS, PCS	
QMOD/QDEM	130 MHz Shifter QMOD			7.7 mA	CDMA	
	85 MHz Shifter + QDEM			7.8 mA	CDMA	
	Offset Mix + QMOD + AGC (90	0 MHz)	2.9 V	39.0 mA	PDC	
	VCO + QMOD + AGC (200 MH	z)		22.0 mA	CDMA	
	Lo = 250 MHz, IF = 10.8 MHz 2	nd Mixer		3.5 mA	PHS	
2 nd Mixer	Lo = 130 MHz, IF = 450 kHz 2n	d Mixer		3.0 mA	PDC	
	400 MHz IF AMP + 2nd Mixer		5.0 mA	GSM/DCS, PCS		
	800 MHz, 1.9 GHz UpCONV		3.0 V	10.2 mA	CDMA	
	1.3-1.6 GHz Local Buffer AMP			3.0 mA	GSM/DCS, PCS	
Buf AMDA/CO	400 MHz VCO + VCO Buffer			5.0 mA	GSM/DCS, PCS	
2 nd Mixer Buf AMP/VCO	260 MHz VCO (Tx)			3.0 mA	CDMA	
	170 MHz VCO (Rx)			1.6 mA	CDMA	
Lim AMP/RSSI	450 KHz LimAMP/RSSI		3.0 V	2.0 mA	PDC	
10.8 MHz LimAMP/RSSI			3.0 V	2.0 mA	PHS	
	130 MHz AGC	G _P = 40 dB	3.6 V	19.0 mA	-CDMA	
AGC AMP	130 WITZ AGC	G _P = 55 dB	3.0 V	4.9 mA		
	850 MHz, 19 GHz AGC + Powe	er driver	3.0 V	38.5 mA	CDMA	

Note: Circuit format and other details can be adjusted to meet customer requirements.

Refer to macro specification book.

■ MACRO BROCHURE

A macro brochure is available for the convenience of customers using standard FUJITSU macros in Astro-NT development. Astro-NT can be arranged in a variety of configurations using combinations of macros. Customer may select the macros that suit their particular requirements for specifications and characteristics. Also, standard macros may be modified to meet more detailed customer requirements.

The macro brochure includes sample applications and electrical characteristics of macros.

Macro Brochure (Sample Macro Electrical Characteristics)
 RV001QMOD (900 MHz Doubler QMOD + AGC)

 $(Vcc = 3.0 \text{ V}, Ta = -25 ^{\circ}C)$

Parameter	Symbol	Та	rget Val	ue	Unit		/Condition	
rarameter	Syllibol	Min.	Тур.	Max.	Ollit	Comment/Condition		
Lo input frequency	fMODLO	870	948	960	MHz	-	_	
Lo input level	PMODLO	-23	-20	-15	dBm	-	_	
I/Q input frequency	fBB	DC	_	0.5	MHz	-	_	
I/Q input amplitude	VBB	0.5	1.0	1.2	Vpp	Single ended input		
I/Q offset voltage	VOS	1.4	1.5	1.6	V	External offset voltag	e value	
I/Q offset current	IOS	_	10	20	μΑ	-	_	
AGCcnt input voltage	AGCcnt	0.7	_	2.5	V	-	_	
SSB maximum output level	Pout1	-1.0	2.0	_	dBm	AGCcnt = 2.5 V		
SSB minimum output	Pout2	-32	_	_	dBm	AGCcnt = 1.1 V	fMODLO = 948 MHz PMODLO = -20 dBm	
level	Foulz	_	_	-32	dBm	AGCcnt = 0.7 V	I/Q : sin, cos wave	
Carrier leakage	CL	_		-30	dBc		5.25 kHz VBB = 1.0 V	
Image rejection	IR			-30	dBc		Single ended	
Third order intermodulation distortion	IM	_		-35	dBc			
Vector error	EVM	_	3.0	5	%	AGCcnt = 0.7 to 2.5V		
Amplitude error	Aerr	_	_	_	%			
Phase error	Perr	_	1.5	_	deg		PMODLO = -20 dBm I/Q : PN9	
Adjacent cannel leak-	ACP	_	-65 *1	-60 *1	dB		, 4	
age power	AOF		-73 * ²	-68 * ²	dB			
TXout1-2 isolation	ISOout	_	30	_	dB	_		
Power supply current	Icc	_	35	_	mA	_		

^{*1:50} kHz offset

^{*2:100} kHz offset

^{*:}Macro brochures are available by contacting your Fujitsu marketing representative.

■ DEVELOPMENT FLOW

Products are developed through the following processes. The illustration below shows the development flow.

(1) Customer Request (Phase 1)

The customer selects an existing macro from the Fujitsu Macro Brochure, for the purpose of producing a system block in a specific design. If the desired macro does not exist, the customer may request Fujitsu to modify an existing macro.

(2) Functional Study and Price Approximation (Phase 2)

Based on the customer request, Fujitsu and the customer make an initial study of feasibility. An initial price estimate is also made.

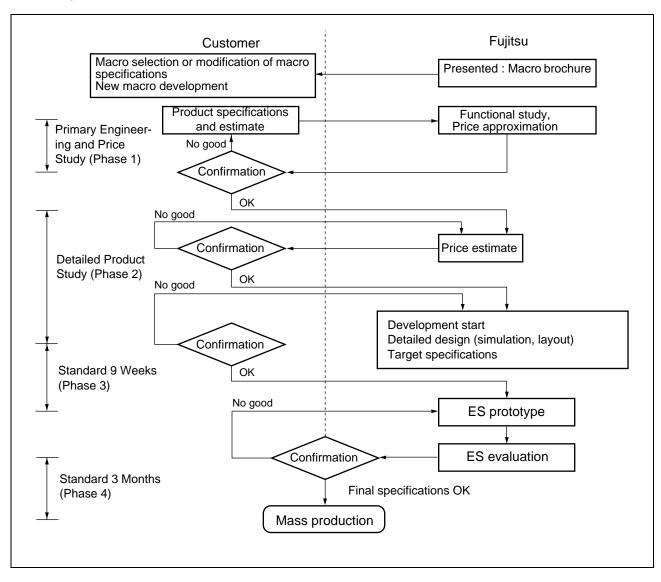
(3) Development Start (Phase 3)

Based on the results of the primary study, and with the approval of the customer, Fujitsu starts the development process. Detailed investigation is made including circuit study and simulation of circuit characteristics, a layout is created, and provisional delivery characteristics (target specifications) are drawn up. The development schedule, development costs, and price estimate are prepared.

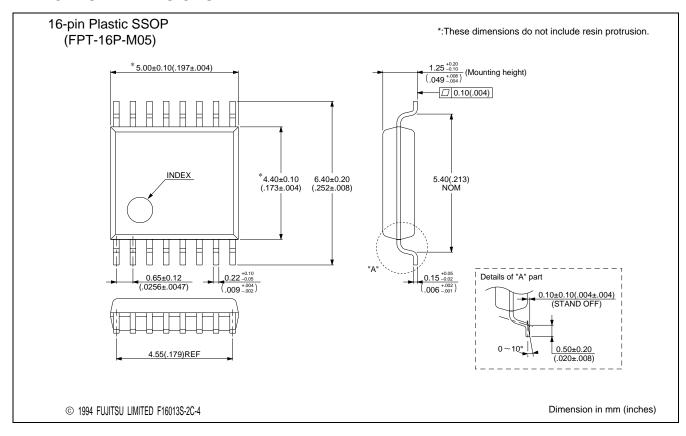
(4) Prototyping and Mass Production

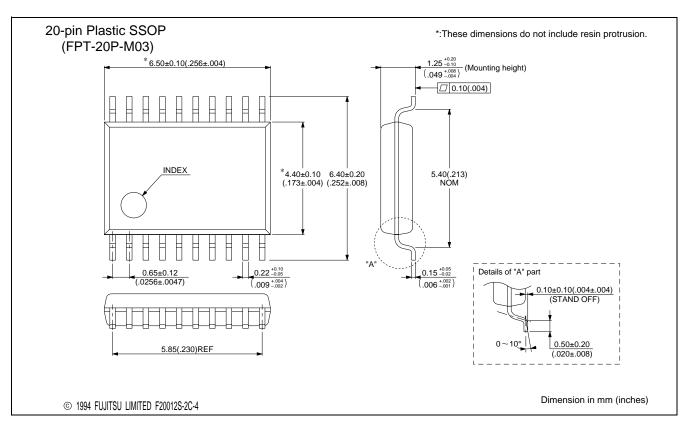
Based on the provisional delivery specifications approved by the customer, the LSI is designed and prototyped. The standard time for ES prototyping is approximately nine weeks. Fujitsu and the customer jointly evaluate the ES based on the provisional specifications. If no problems are found, final delivery specifications are approved and development is completed. The next step, transition to mass production and delivery, requires a standard interval of approximately three months.

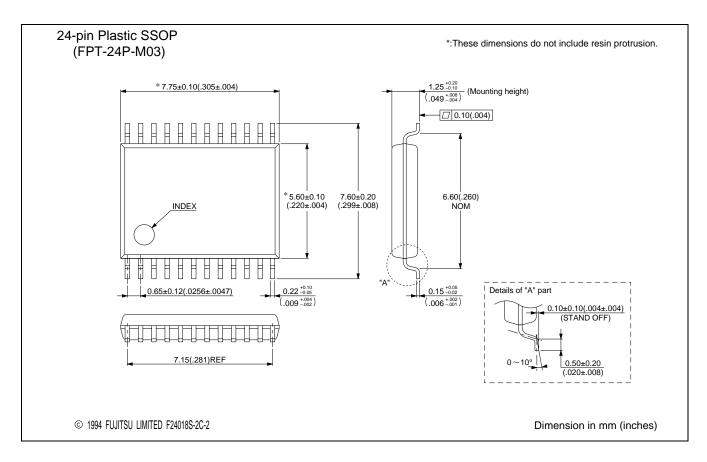
• Development Flow

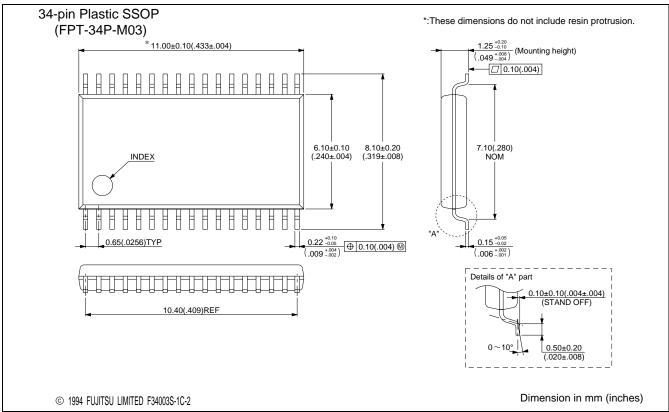


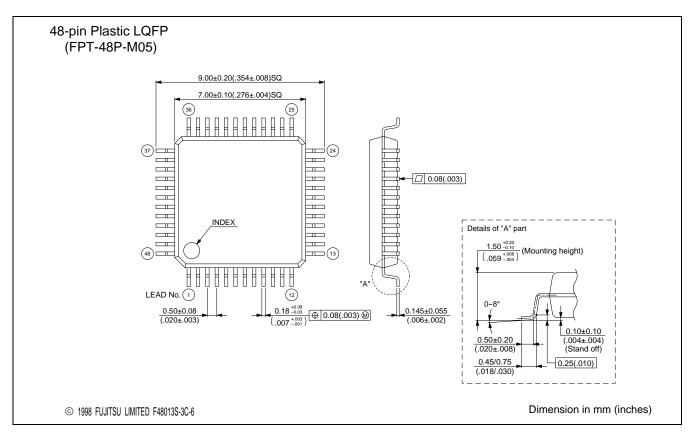
■ PACKAGE DIMENSIONS

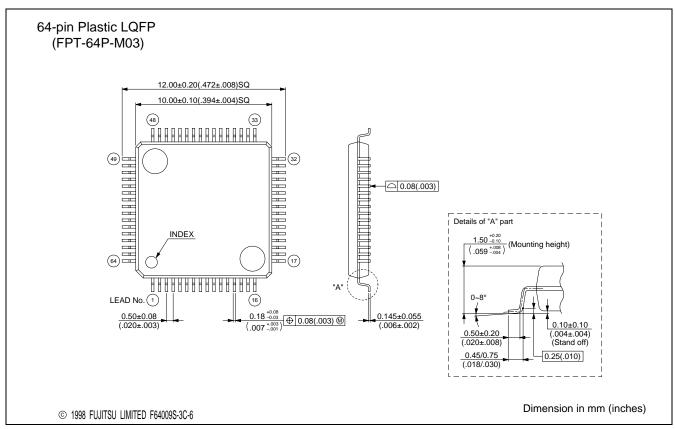


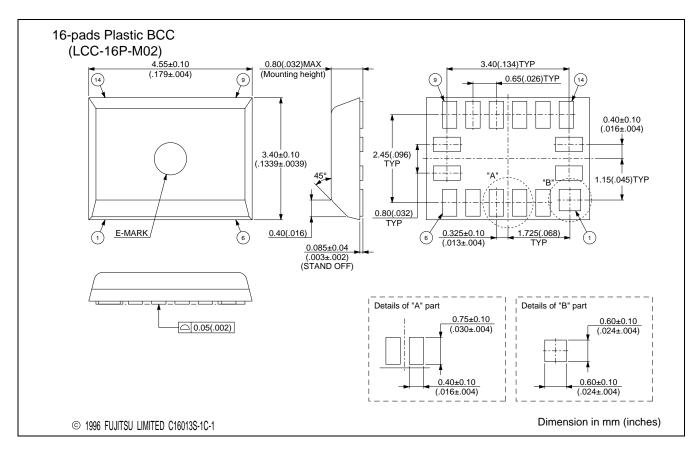


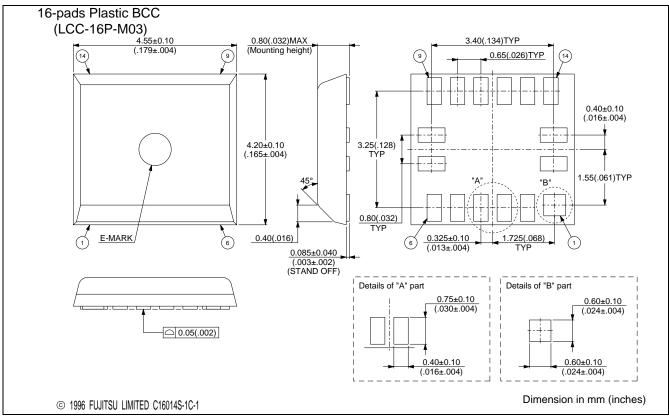


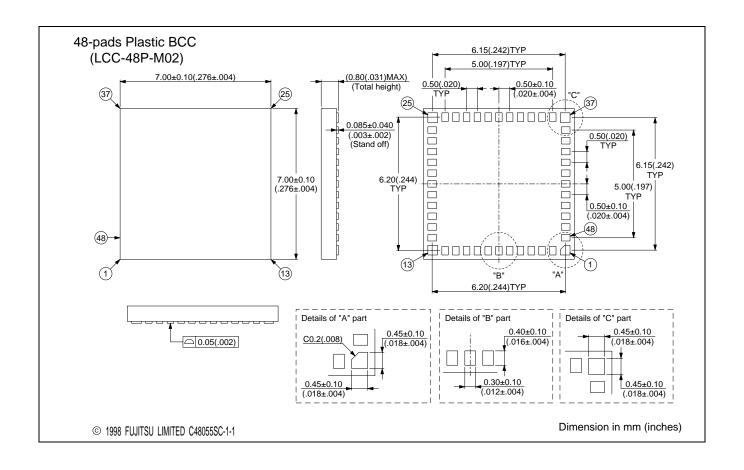












■ ASTRO-NT REQUEST SHEET (Example)

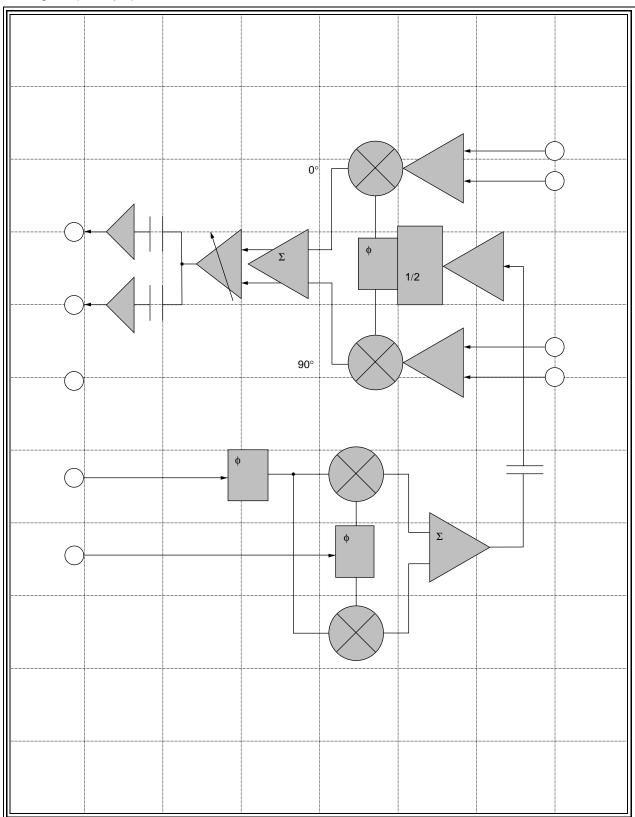
Customer nar	me :			
Application	:			
Time	:ES;	CS;		
Quantity	:			
Macro r	name (*1)		Use current specifications	Modification requested (*2)
RV00)1AMP		×	
RV00	02MIX			×
RV001	1QMOD			×
·				

If Modification is Requested:

Macro name: RV002MIX, RV001QMOD

Function	Davamatav	Targe Sumbal		get Value		l lmi4	Unit Comment/Condition
Block	Parameter	Symbol	Min.	Тур.	Max.	Unit	Comment/Condition
RV002 MIX	Gaim	Gv		30		dB	
RV001 QMOD	SSB maximum output level	Pout1	-2	2		dBm	AGCcnt = 2.0 V

Block diagram (Example)



■ ASTRO-NT REQUEST SHEET

:			
:			
:ES;	CS;		
:			
e (*1)		Use current specifications	Modification requested (*2)
	=		
	=		
	=		
	=		
	=		
	-		
	: :ES; :	: :ES; CS; :	: :ES; CS; : Use current

^{*:}Please fill in the macro name of the macro brochure.

^{*:}Please fill in the demand on an attached spec seat.

Macro name:

Function	Parameter	Symbol	Taı	get Va	lue	Unit	Comment/Condition
Block	Parameter	Symbol	Min.	Тур.	Max.	Onit	Comment/Condition

Block diagram

FUJITSU LIMITED

For further information please contact:

Japan

FUJITSU LIMITED
Corporate Global Business Support Division
Electronic Devices
KAWASAKI PLANT, 4-1-1, Kamikodanaka

Nakahara-ku, Kawasaki-shi Kanagawa 211-8588, Japan

Tel: 81(44) 754-3763 Fax: 81(44) 754-3329

http://www.fujitsu.co.jp/

North and South America

FUJITSU MICROELECTRONICS, INC. Semiconductor Division 3545 North First Street San Jose, CA 95134-1804, USA

Tel: (408) 922-9000 Fax: (408) 922-9179

Customer Response Center Mon. - Fri.: 7 am - 5 pm (PST)

Tel: (800) 866-8608 Fax: (408) 922-9179

http://www.fujitsumicro.com/

Europe

FUJITSU MIKROELEKTRONIK GmbH Am Siebenstein 6-10 D-63303 Dreieich-Buchschlag Germany

Tel: (06103) 690-0 Fax: (06103) 690-122

http://www.fujitsu-ede.com/

Asia Pacific

FUJITSU MICROELECTRONICS ASIA PTE LTD #05-08, 151 Lorong Chuan

New Tech Park Singapore 556741 Tel: (65) 281-0770 Fax: (65) 281-0220

http://www.fmap.com.sg/

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